

Yida Li

List of Publications by Year in descending order

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42
papers

1,201
citations

430754

18
h-index

454834

30
g-index

44
all docs

44
docs citations

44
times ranked

2039
citing authors

#	ARTICLE	IF	CITATIONS
1	Contact Resistance Reduction of Low Temperature Atomic Layer Deposition ZnO Thin Film Transistor Using Ar Plasma Surface Treatment. IEEE Electron Device Letters, 2022, 43, 890-893.	2.2	10
2	Performance Optimization of Atomic Layer Deposited HfO _x Memristor by Annealing With Back-End-of-Line Compatibility. IEEE Electron Device Letters, 2022, 43, 1141-1144.	2.2	9
3	Wafer-scale solution-processed 2D material analog resistive memory array for memory-based computing. Nature Communications, 2022, 13, .	5.8	60
4	Field-Effect Mobility Enhancement in Low Temperature ALD ZnO Thin-film Transistors via Contact Defects Engineering Suitable for BEOL Integration. , 2022, , .		0
5	Transfer Learning-Based Artificial Intelligence-Integrated Physical Modeling to Enable Failure Analysis for 3 Nanometer and Smaller Silicon-Based CMOS Transistors. ACS Applied Nano Materials, 2021, 4, 6903-6915.	2.4	25
6	A 70- μ W 1.35-mm ² Wireless Sensor With 32 Channels of Resistive and Capacitive Sensors and Edge-Encoded PWM UWB Transceiver. IEEE Journal of Solid-State Circuits, 2021, 56, 2065-2076.	3.5	6
7	Hybrid-Flexible Bimodal Sensing Wearable Glove System for Complex Hand Gesture Recognition. ACS Sensors, 2021, 6, 4156-4166.	4.0	26
8	A highly sensitive graphene oxide based label-free capacitive aptasensor for vanillin detection. Materials and Design, 2020, 186, 108208.	3.3	27
9	A 7 x 7 x 2 mm ³ 8.6- μ W 500-kb/s Transmitter With Robust Injection-Locking-Based Frequency-to-Amplitude Conversion Receiver Targeting for Implantable Applications. IEEE Journal of Solid-State Circuits, 2020, , 1-11.	3.5	5
10	An 8.2- μ W 0.14-mm ² 16-Channel CDMA-Like Capacitance-to-Digital Converter. IEEE Journal of Solid-State Circuits, 2020, 55, 1361-1373.	3.5	10
11	A Wireless Multi-Channel Capacitive Sensor System for Efficient Glove-Based Gesture Recognition With AI at the Edge. IEEE Transactions on Circuits and Systems II: Express Briefs, 2020, 67, 1624-1628.	2.2	29
12	23.2 A 70- μ W 1.19mm ² Wireless Sensor with 32 Channels of Resistive and Capacitive Sensors and Edge-Encoded PWM UWB Transceiver. , 2020, , .		4
13	Fledge: Flexible Edge Platforms Enabled by In-memory Computing. , 2020, , .		2
14	Aerosol Jet Printed WSe ₂ Crossbar Architecture Device on Kapton With Dual Functionality as Resistive Memory and Photosensor for Flexible System Integration. IEEE Sensors Journal, 2020, 20, 4653-4659.	2.4	15
15	Low Subthreshold Swing and High Mobility Amorphous Indium-Gallium-Zinc-Oxide Thin-Film Transistor With Thin HfO ₂ Gate Dielectric and Excellent Uniformity. IEEE Electron Device Letters, 2020, 41, 856-859.	2.2	48
16	Seal Integrity Testing Utilizing Non-Destructive Capacitive Sensing for Product Packaging Assurance. , 2020, , .		2
17	A 7-7-2mm ³ 8.6- μ W 500-kb/s Transmitter with Robust Injection-Locking Based Frequency-to-Amplitude Conversion Receiver Targeting for Implantable Applications. , 2019, , .		1
18	First Demonstration of a Fully-Printed Mos2Rram on Flexible Substrate with Ultra-Low Switching Voltage and its Application as Electronic Synapse. , 2019, , .		8

#	ARTICLE	IF	CITATIONS
19	Liquid-metal-elastomer foam for moldable multi-functional triboelectric energy harvesting and force sensing. <i>Nano Energy</i> , 2019, 64, 103912.	8.2	37
20	All WSe ₂ 1T1R resistive RAM cell for future monolithic 3D embedded memory integration. <i>Nature Communications</i> , 2019, 10, 5201.	5.8	107
21	A Fully Printed Flexible MoS ₂ Memristive Artificial Synapse with Femtojoule Switching Energy. <i>Advanced Electronic Materials</i> , 2019, 5, 1900740.	2.6	123
22	Aerosol Jet Printed WSe ₂ Based RRAM on Kapton Suitable for Flexible Monolithic Memory Integration. , 2019, , .		6
23	Design of Artificial Spiking Neuron with SiO ₂ Memristive Synapse to Demonstrate Neuron-Level Spike Timing Dependent Plasticity. , 2019, , .		0
24	Impact of Ti Interfacial Layer on Resistive Switching Characteristics at sub- μ A Current Level in SiO _x -Based Flexible Cross-Point RRAM. , 2019, , .		2
25	A Soft Polydimethylsiloxane Liquid Metal Interdigitated Capacitor Sensor and Its Integration in a Flexible Hybrid System for On-Body Respiratory Sensing. <i>Materials</i> , 2019, 12, 1458.	1.3	28
26	A flexible InGaAs nanomembrane PhotoFET with tunable responsivities in near- and short-wave IR region for lightweight imaging applications. <i>APL Materials</i> , 2019, 7, .	2.2	13
27	Highly Scaled Strained Silicon-On-Insulator Technology for the 5G Era: Impact of Geometry and Annealing on Strain Retention and Device Performance of nMOSFETs. <i>IEEE Transactions on Electron Devices</i> , 2019, 66, 2068-2074.	1.6	4
28	A Stretchable ϵ -Hybrid Low ϵ -Power Monolithic ECG Patch with Microfluidic Liquid ϵ -Metal Interconnects and Stretchable Carbon ϵ -Black Nanocomposite Electrodes for Wearable Heart Monitoring. <i>Advanced Electronic Materials</i> , 2019, 5, 1800463.	2.6	44
29	Design and Study of an Artificial Spiking Neuron Enabled by Low-Voltage SiO _x -based ReRAM. , 2019, , .		0
30	A flexible liquid-metal alloy bandpass filter. <i>International Journal of RF and Microwave Computer-Aided Engineering</i> , 2018, 28, e21265.	0.8	8
31	Bendable and Stretchable Microfluidic Liquid Metal-Based Filter. <i>IEEE Microwave and Wireless Components Letters</i> , 2018, 28, 203-205.	2.0	17
32	A Near- & Short-Wave IR Tunable InGaAs Nanomembrane PhotoFET on Flexible Substrate for Lightweight and Wide-Angle Imaging Applications. , 2018, , .		1
33	Raman analysis of gold on WSe ₂ single crystal film. <i>Materials Research Express</i> , 2015, 2, 065009.	0.8	20
34	Tuning the threshold voltage of MoS ₂ field-effect transistors via surface treatment. <i>Nanoscale</i> , 2015, 7, 10823-10831.	2.8	71
35	Low Resistance Metal Contacts to MoS ₂ Devices with Nickel-Etched-Graphene Electrodes. <i>ACS Nano</i> , 2015, 9, 869-877.	7.3	184
36	Suppression of Void Formation in Si _{>0.5} Ge _{>0.5} Alloy Nanowire during Ni Germanosilicidation. <i>Advanced Engineering Materials</i> , 2014, 16, 1032-1037.	1.6	0

#	ARTICLE	IF	CITATIONS
37	Effect of Electrical Contact Resistance in a Silicon Nanowire Thermoelectric Cooler and a Design Guideline for On-Chip Cooling Applications. Journal of Electronic Materials, 2013, 42, 1476-1481.	1.0	9
38	Vertical Silicon Nanowire Platform for Low Power Electronics and Clean Energy Applications. Journal of Nanotechnology, 2012, 2012, 1-21.	1.5	35
39	Top-Down Silicon Nanowire-Based Thermoelectric Generator: Design and Characterization. Journal of Electronic Materials, 2012, 41, 989-992.	1.0	30
40	Improved Vertical Silicon Nanowire Based Thermoelectric Power Generator With Polyimide Filling. IEEE Electron Device Letters, 2012, 33, 715-717.	2.2	60
41	Chip-Level Thermoelectric Power Generators Based on High-Density Silicon Nanowire Array Prepared With Top-Down CMOS Technology. IEEE Electron Device Letters, 2011, 32, 674-676.	2.2	105
42	Silicon nanowires thermoelectric devices. , 2010, , .		2